NSN 5961-00-113-0025

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Inclosure Material:

Metal

Overall Length:

1.237 inches

Overall Diameter:

Between 0.410 inches and 0.430 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.552 inches and 0.567 inches

Thread Size:

0.3125 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

160.0 collector to base voltage/static/emitter open and 120.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

10.00 amperes source cutoff current

Power Rating Per Characteristic:

40.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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- Demilitarization:
- Yes demil/mli

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